SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

General Description

The MAX4475–MAX4478/MAX4488/MAX4489 wideband, low-noise, low-distortion operational amplifiers offer rail-to-rail outputs and single-supply operation down to 2.7V. They draw 2.2mA of quiescent supply current per amplifier while featuring ultra-low distortion (0.0002% THD+N), as well as low input voltage-noise density (4.5nV/ \sqrt{Hz}) and low input current-noise density (0.5fA/ \sqrt{Hz}). These features make the devices an ideal choice for applications that require low distortion and/or low noise.

For power conservation, the MAX4475/MAX4488 offer a low-power shutdown mode that reduces supply current to 0.01µA and places the amplifiers' outputs into a high-impedance state. These amplifiers have outputs which swing rail-to-rail and their input common-mode voltage range includes ground. The MAX4475–MAX4478 are unity-gain stable with a gain-bandwidth product of 10MHz. The MAX4488/4489 are internally compensated for gains of +5V/V or greater with a gain-bandwidth product of 42MHz. The single MAX4475/MAX4476/ MAX4488 are available in space-saving, 6-pin SOT23 and TDFN packages.

Applications

- ADC Buffers
- DAC Output Amplifiers
- Low-Noise Microphone/Preamplifiers
- Digital Scales
- Strain Gauges/Sensor Amplifiers
- Medical Instrumentation
- Automotive

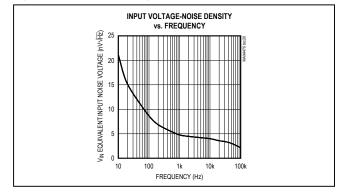
µMAX is a registered trademark of Maxim Integrated Products, Inc.

Features

- Low Input Voltage-Noise Density: 4.5nV/√Hz
- Low Input Current-Noise Density: 0.5fA/√Hz
- Low Distortion: 0.0002% THD+N (1kΩ load)
- Single-Supply Operation from +2.7V to +5.5V
- Input Common-Mode Voltage Range Includes Ground
- Rail-to-Rail Output Swings with a $1k\Omega$ Load
- 10MHz GBW Product, Unity-Gain Stable (MAX4475–MAX4478)
- 42MHz GBW Product, Stable with AV ≥ +5V/V (MAX4488/MAX4489)
- Excellent DC Characteristics V_{OS} = 70µV
 - $I_{BIAS} = 1pA$
 - Large-Signal Voltage Gain = 120dB
- Low-Power Shutdown Mode:
- Reduces Supply Current to 0.01µA
- Places Output in High-Impedance State
- Available in Space-Saving SOT23, TDFN, $\mu MAX \circledast,$ and TSSOP Packages
- AEC-Q100 Qualified, Refer to Ordering Information for the List of /V Parts

Ordering Information at end of data sheet.

Typical Operating Characteristic



Pin Configurations and Typical Operating Circuit appear at end of data sheet.



SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Absolute Maximum Ratings

Power-Supply Voltage (V _{DD} to V _{SS})	0.3V to +6.0V
Analog Input Voltage (IN_+, IN).(V _{SS} - 0.3V) to	(V _{DD} + 0.3V)
SHDN Input Voltage(V _{SS} - 0	.3V) to +6.0V
Output Short-Circuit Duration to Either Supply	Continuous
Continuous Input Current (IN+, IN-)	±10mA
Continuous Power Dissipation (T _A = +70°C)	
6 Din COT22 (denote E $4m/M/^{\circ}C$ shows $\pm 70^{\circ}C$)	404 0mm\A/

6-Pin SOT23 (derate 5.4mW/°C above +70°C)431.3mW 6-Pin TDFN (derate 18.2mW/°C above 70°C)1454mW 8-Pin μMAX (derate 4.5mW/°C above +70°C)......362mW

8-Pin SO (derate 5.88mW/°C above +70°C)471mW	
14-Pin SO (derate 8.33mW/°C above +70°C)667mW	
14-Pin TSSOP (derate 9.1mW/°C above +70°C)727mW	
Operating Temperature Range40°C to +125°C	
Junction Temperature+150°C	
Storage Temperature Range65°C to +150°C	
Lead Temperature (soldering, 10s)+300°C	
Soldering Temperature (reflow)+260°C	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

SOT23-6

PACKAGE CODE	U6F+6
Outline Number	<u>21-0058</u>
Land Pattern Number	<u>90-0175</u>
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ_{JA})	185.5°C/W
Junction to Case (θ_{JC})	75°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	134.4°C/W
Junction to Case (θ _{JC})	39°C/W

µMAX-8

PACKAGE CODE	U8+4
Outline Number	<u>21-0036</u>
Land Pattern Number	<u>90-0092</u>
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	206°C/W
Junction to Case (θ_{JC})	42

µMAX-8

PACKAGE CODE	U8+1
Outline Number	21-0036
Land Pattern Number	<u>90-0092</u>
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ_{JA})	221°C/W
Junction to Case (θ_{JC})	42°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	206°C/W
Junction to Case (θ_{JC})	42°C/W

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Package Information (continued)

TSSOP-14

PACKAGE CODE	U14+2
Outline Number	<u>21-0066</u>
Land Pattern Number	<u>90-0113</u>
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ_{JA})	110°C/W
Junction to Case (θ _{JC})	30°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	100.4°C/W
Junction to Case (θ_{JC})	30°C/W

SO-8

PACKAGE CODE	S8+4
Outline Number	<u>21-0041</u>
Land Pattern Number	90-0096
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ _{JA})	170°C/W
Junction to Case (θ_{JC})	40
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ _{JA})	132°C/W
Junction to Case (θ_{JC})	38

SO-14

PACKAGE CODE	S14+4
Outline Number	21-0041
Land Pattern Number	<u>90-0112</u>
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ_{JA})	120°C/W
Junction to Case (θ_{JC})	37°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	84°C/W
Junction to Case (θ_{JC})	34°C/W

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Package Information (continued)

TDFN-6

PACKAGE CODE	T633+2
Outline Number	<u>21-0137</u>
Land Pattern Number	90-0058
Thermal Resistance, Single-Layer Board	
Junction to Ambient (θ_{JA})	55°C/W
Junction to Case (θ_{JC})	9°C/W
Thermal Resistance, Multi-Layer Board	
Junction to Ambient (θ_{JA})	42°C/W
Junction to Case (θ _{JC})	9°C/W

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

DC Electrical Characteristics

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \text{ SHDN} = V_{DD}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C}.)$ (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS
Supply Voltage Range	V _{DD}	(Note 3)		2.7		5.5	V	
		Normalmada		V _{DD} = 3V		2.2		~^
Quiescent Supply Current Per Amplifier	I _D	Normal mode		V _{DD} = 5V		2.5	4.4	mA
, anpinoi		Shutdown mode	(SHDN =	= V _{SS}) (Note 2)		0.01	1.0	μA
Innut Offeet Veltere	N	T _A = +25°C				±70	±350	
Input Offset Voltage	V _{OS}	$T_A = -40^{\circ}C \text{ to } +12^{\circ}C$	25°C				±750	μV
Input Offset Voltage Tempco	TC _{VOS}					±0.3	±6	µV/°C
Input Bias Current	Ι _Β	(Note 4)				±1	±150	pА
Input Offset Current	I _{OS}	(Note 4)				±1	±150	pА
Differential Input Resistance	R _{IN}					1000		GΩ
Input Common-Mode Voltage	Mara	Guaranteed by	T _A = +	25°C	-0.2		V _{DD} - 1.6	V
Range	V _{CM}	CMRR Test	T _A = -4	40°C to +125°C	-0.1		V _{DD} - 1.7	v
Common Made Poinction Potio	CMPR	$(V_{SS} - 0.2V) \le V_{CM} \le (V_{DD} - 1.6V)$	T _A = +	T _A = +25°C		115		dP
Common-Mode Rejection Ratio	CMRR	$(V_{SS} - 0.1V) \le V_{CM} \le (V_{DD} - T_A = -40^{\circ}C \text{ to } +125^{\circ}C = 1.7V)$		90			dB	
Power-Supply Rejection Ratio	PSRR	V _{DD} = 2.7 to 5.5V		90	120		dB	
		R_L = 10kΩ to V _{DD} /2; V _{OUT} = 100mV to (V _{DD} - 125mV)			90	120		
Large-Signal Voltage Gain	A _{VOL}	$R_L = 1k\Omega$ to V_{DD} $V_{OUT} = 200 \text{mV}$ to	/2; p (V _{DD} -	250mV)	85	110		dB
		$R_L = 500\Omega$ to V _D V _{OUT} = 350mV to	_D /2; p (V _{DD} -	500mV)	85	110		
		V _{IN+} - V _{IN-} ≥ 10	mV.	V _{DD} - V _{OH}		10	45	
		$R_L = 10k\Omega$ to V_{DI}	D/2	V _{OL} - V _{SS}		10	40	
Outer the last Outer	N	V _{IN+} - V _{IN-} ≥ 10	≥ 10mV. V _{DD} - V _C	V _{DD} - V _{OH}		80	200	mV
Output Voltage Swing	V _{OUT}	$R_L = 1k\Omega$ to V_{DD}	/2	V _{OL} - V _{SS}		50	150	
		IV _{INI+} - V _{INI} ≥ 10mV.	V _{IN+} - V _{IN-} ≥ 10mV, V _{DD} - V _{OH}		100	300		
		$R_L = 500\Omega$ to $V_{DD}/2$		V _{OL} - V _{SS}		80	250	
Output Short-Circuit Current	I _{SC}					48		mA
Output Leakage Current	I _{LEAK}	Shutdown mode ($\overline{SHDN} = V_{SS}$), V _{OUT} = V _{SS} to V _{DD}			±0.001	±1.0	μA	
SHDN Logic-Low	VIL						0.3 x V _{DD}	V
SHDN Logic-High	VIH			0.7 x V _{DD}			V	
SHDN Input Current		$\overline{\text{SHDN}} = V_{SS} \text{ to } V_{DD}$				0.01	1	μA
Input Capacitance	C _{IN}				10		pF	

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

AC Electrical Characteristics

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITI	ONS	MIN TYP	MAX	UNITS	
		MAX4475–MAX4478	$A_V = +1V/V$	10			
Gain-Bandwidth Product	GBWP	MAX4488/MAX4489 A _V = +5V/V		42		MHz	
Olaw Data	0.0	MAX4475-MAX4478	$A_V = +1V/V$	3		V/µs	
Slew Rate	SR	MAX4488/MAX4489	$A_V = +5V/V$	10			
Full Dower Dondwidth (Note 5)		MAX4475-MAX4478	$A_V = +1V/V$	0.4		MHz	
Full-Power Bandwidth (Note 5)		MAX4488/MAX4489	$A_V = +5V/V$	1.25			
Peak-to-Peak Input Noise Voltage	e _{n(P-P)}	f = 0.1Hz to 10Hz		260		nVp_p	
		f = 10Hz		21	21		
Input Voltage-Noise Density	e _n	f = 1kHz		4.5		nV/√Hz	
		f = 30kHz		3.5			
Input Current-Noise Density	i _n	f = 1kHz		0.5		fA/√Hz	
		V _{OUT} = 2V _{P-P} , A _V = +1V/V	f = 1kHz	0.0002			
	THD + N	(MAX4475–MAX4478), R _L = 10kΩ to GND	f = 20kHz	0.0007		%	
Total Harmonic Distortion Plus		$V_{OUT} = 2V_{P-P}, A_V = +1V/V$ (MAX4475–MAX4478), R _L = 1k Ω to GND	f = 1kHz	0.0002			
Noise (Note 6)			f = 20kHz	0.001			
		V _{OUT} = 2V _{P-P} , A _V = +5V/V (MAX4488/	f = 1kHz	0.0004			
		\dot{M} AX4489), R _L = 10k Ω to GND	f = 20kHz	0.0006			
Total Harmonic Distortion Plus		V _{OUT} = 2V _{P-P} , A _V = +5V/V	f = 1kHz	0.0005			
Noise (Note 6)	THD + N	(MAX4488/MAX4489), $R_L = 1k\Omega$ to GND	f = 20kHz	0.008		%	
Capacitive-Load Stability		No sustained oscillations	No sustained oscillations			pF	
Gain Margin	GM			12		dB	
Phase Margin		MAX4475–MAX4478, A _V = +1V/V		70			
	ФМ	MAX4488/MAX4489, $A_{V} = +5V/V$		80		degrees	
Settling Time		To 0.01%, V _{OUT} = 2V st	2		μs		
Delay Time to Shutdown	t _{SH}		1.5		μs		
Enable Delay Time from Shutdown		V _{OUT} = 2.5V, V _{OUT} sett	log to 0 1%	1.5			
•	t _{EN}				μs		
Power-Up Delay Time		V _{DD} = 0 to 5V step, V _{OL}	13		μs		

Note 1: All devices are 100% tested at $T_A = +25^{\circ}C$. Limits over temperature are guaranteed by design.

Note 2: SHDN is available on the MAX4475/MAX4488 only.

Note 3: Guaranteed by the PSRR test.

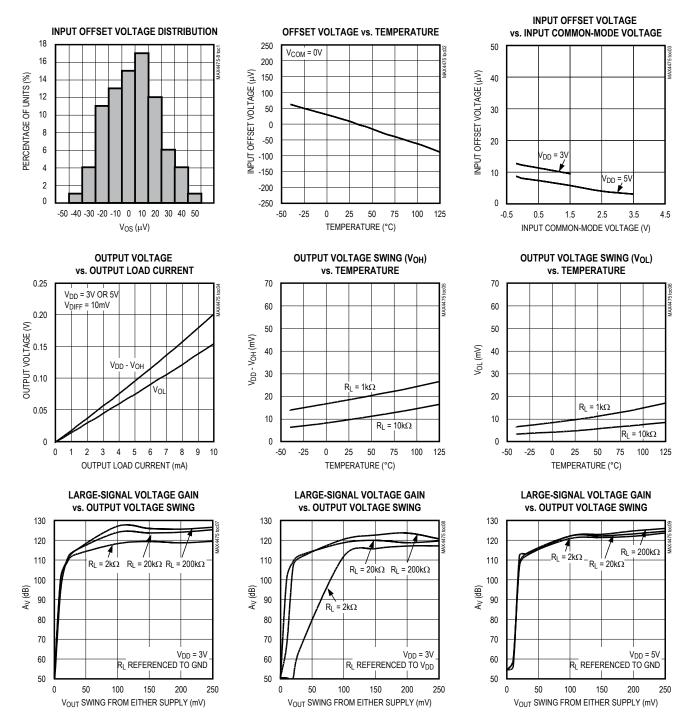
Note 4: Guaranteed by design.

Note 5: Full-power bandwidth for unity-gain stable devices (MAX4475–MAX4478) is measured in a closed-loop gain of +2V/V to accommodate the input voltage range, V_{OUT} = 4V_{P-P}.

Note 6: Lowpass-filter bandwidth is 22kHz for f = 1kHz and 80kHz for f = 20kHz. Noise floor of test equipment = $10nV/\sqrt{Hz}$.

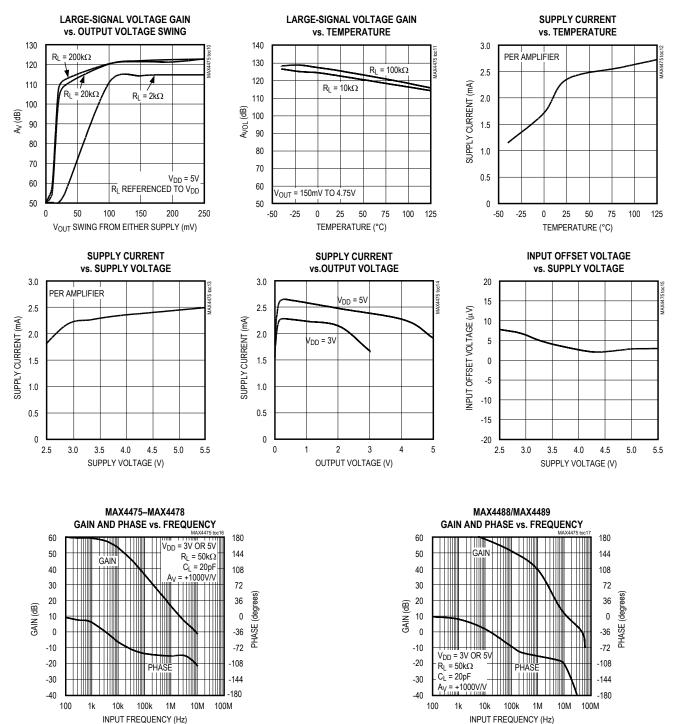
SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Typical Operating Characteristics



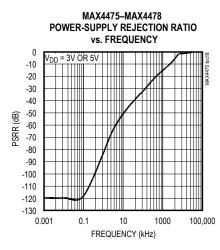
SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

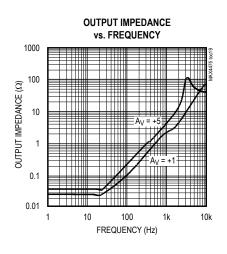
Typical Operating Characteristics (continued)

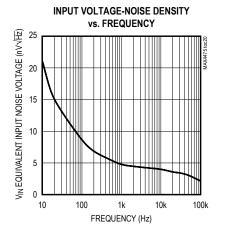


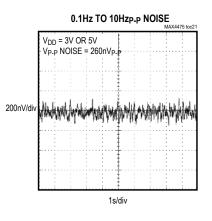
SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

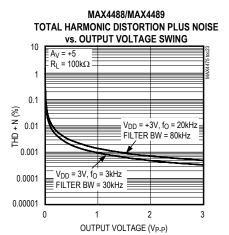
Typical Operating Characteristics (continued)

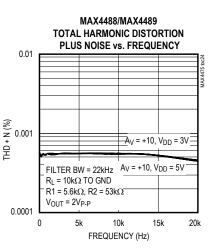




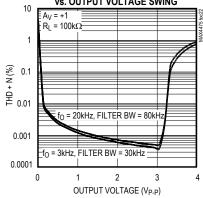




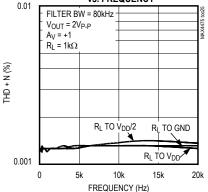






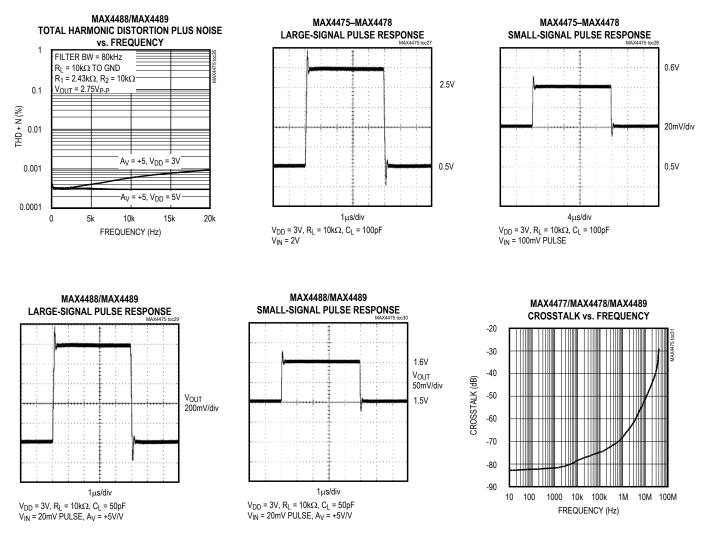


MAX4475-MAX4478 TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY



SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Typical Operating Characteristics (continued)



SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Pin Description

		PIN				
MAX4475/ MAX4488	MAX4475/ MAX4488	MAX4476	MAX4477/ MAX4489	MAX4478	NAME	FUNCTION
SOT23/TDFN	SO/µMAX	SOT23/TDFN	SO/µMAX	SO/TSSOP		
1	6	1	1, 7	1, 7, 8, 14	OUT, OUTA, OUTB, OUTC, OUTD	Amplifier Output
2	4	2	4	11	V _{SS}	Negative Supply. Connect to ground for single-supply operation
3	3	3	3, 5	3, 5, 10, 12	IN+, INA+, INB+, INC+, IND+	Noninverting Amplifier Input
4	2	4	2, 6	2, 6, 9, 13	IN-, INA-, INB-, INC-, IND-	Inverting Amplifier Input
6	7	6	8	4	V _{DD}	Positive Supply
5	8	_	_	_	SHDN	Shutdown Input. Connect to V_{DD} for normal operation (amplifier(s) enabled).
	1, 5	5		_	N.C.	No Connection. Not internally connected.
EP	_	EP	_	_	EP	Exposed Paddle (TDFN Only). Connect to V _{SS} .

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Detailed Description

The MAX4475–MAX4478/MAX4488/MAX4489 singlesupply operational amplifiers feature ultra-low noise and distortion. Their low distortion and low noise make them ideal for use as preamplifiers in wide dynamic-range applications, such as 16-bit analog-to-digital converters (see *Typical Operating Circuit*). Their high-input impedance and low noise are also useful for signal conditioning of high-impedance sources, such as piezoelectric transducers.

These devices have true rail-to-rail output operation, drive loads as low as $1k\Omega$ while maintaining DC accuracy, and can drive capacitive loads up to 200pF without oscillation. The input common-mode voltage range extends from (V_{DD} - 1.6V) to 200mV below the negative rail. The push-pull output stage maintains excellent DC characteristics, while delivering up to ±5mA of current.

The MAX4475–MAX4478 are unity-gain stable, while the MAX4488/MAX4489 have a higher slew rate and are stable for gains \geq 5V/V. The MAX4475/MAX4488 feature a low-power shutdown mode, which reduces the supply current to 0.01µA and disables the outputs.

Low Distortion

Many factors can affect the noise and distortion that the device contributes to the input signal. The following guidelines offer valuable information on the impact of design choices on Total Harmonic Distortion (THD).

Choosing proper feedback and gain resistor values for a particular application can be a very important factor in reducing THD. In general, the smaller the closed-loop gain, the smaller the THD generated, especially when driving heavy resistive loads. The THD of the part normally increases at approximately 20dB per decade, as a function of frequency. Operating the device near or above the full-power bandwidth significantly degrades distortion.

Referencing the load to either supply also improves the part's distortion performance, because only one of the MOSFETs of the push-pull output stage drives the output. Referencing the load to midsupply increases the part's distortion for a given load and feedback setting. (See the Total Harmonic Distortion vs. Frequency graph in the *Typical Operating Characteristics.*)

For gains \geq 5V/V, the decompensated devices MAX4488/ MAX4489 deliver the best distortion performance, since they have a higher slew rate and provide a higher amount of loop gain for a given closed-loop gain setting. Capacitive loads below 100pF do not significantly affect distortion results. Distortion performance is relatively constant over supply voltages.

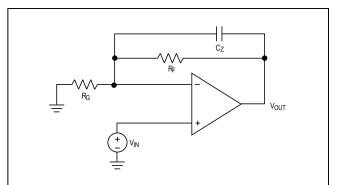


Figure 1. Adding Feed-Forward Compensation

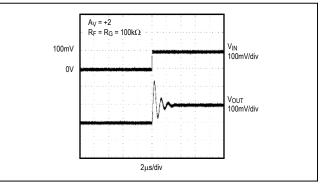


Figure 2a. Pulse Response with No Feed-Forward Compensation

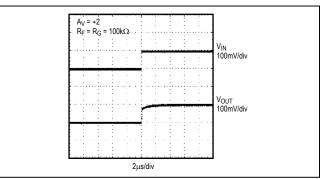


Figure 2b. Pulse Response with 10pF Feed-Forward Compensation

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Low Noise

The amplifier's input-referred noise-voltage density is dominated by flicker noise at lower frequencies, and by thermal noise at higher frequencies. Because the thermal noise contribution is affected by the parallel combination of the feedback resistive network ($R_F \parallel R_G$, Figure 1), these resistors should be reduced in cases where the system bandwidth is large and thermal noise is dominant. This noise contribution factor decreases, however, with increasing gain settings.

For example, the input noise-voltage density of the circuit with $R_F = 100k\Omega$, $R_G = 11k\Omega$ ($A_V = +5V/V$) is $e_n = 14nV/\sqrt{Hz}$, e_n can be reduced to $6nV/\sqrt{Hz}$ by choosing $R_F = 10k\Omega$, $R_G = 1.1k\Omega$ ($A_V = +5V/V$), at the expense of greater current consumption and potentially higher distortion. For a gain of 100V/V with $R_F = 100k\Omega$, $R_G = 1.1k\Omega$, the e_n is still a low $6nV/\sqrt{Hz}$.

Using a Feed-Forward Compensation Capacitor, CZ

The amplifier's input capacitance is 10pF. If the resistance seen by the inverting input is large (feedback network), this can introduce a pole within the amplifier's bandwidth resulting in reduced phase margin. Compensate the reduced phase margin by introducing a feed-forward capacitor (C_Z) between the inverting input and the output (Figure 1). This effectively cancels the pole from the inverting input of the amplifier. Choose the value of C_Z as follows:

$$C_Z = 10 \times (R_F / R_G) [pF]$$

In the unity-gain stable MAX4475–MAX4478, the use of a proper C_Z is most important for A_V = +2V/V, and A_V = -1V/V. In the decompensated MAX4488/MAX4489, C_Z is most important for A_V = +10V/V. Figures 2a and 2b show transient response both with and without C₇.

Using a slightly smaller C_Z than suggested by the formula above achieves a higher bandwidth at the expense of reduced phase and gain margin. As a general guideline, consider using C_Z for cases where R_G || R_F is greater than 20k Ω (MAX4475–MAX4478) or greater than 5k Ω (MAX4488/MAX4489).

Applications Information

The MAX4475–MAX4478/MAX4488/MAX4489 combine good driving capability with ground-sensing input and rail-to-rail output operation. With their low distortion and low noise, they are ideal for use in ADC buffers, medical instrumentation systems and other noise-sensitive applications.

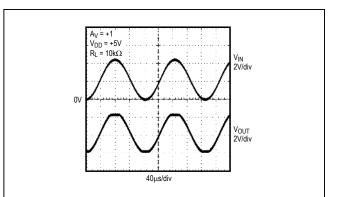


Figure 3. Overdriven Input Showing No Phase Reversal

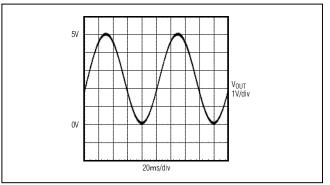


Figure 4. Rail-to-Rail Output Operation

Ground-Sensing and Rail-to-Rail Outputs

The common-mode input range of these devices extends below ground, and offers excellent common-mode rejection. These devices are guaranteed not to undergo phase reversal when the input is overdriven (Figure 3).

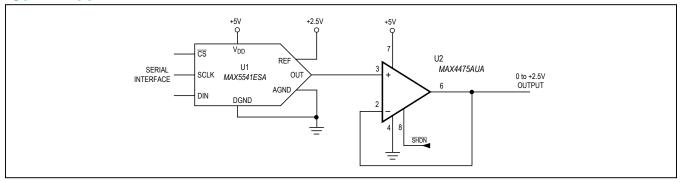
Figure 4 showcases the true rail-to-rail output operation of the amplifier, configured with A_V = 5V/V. The output swings to within 8mV of the supplies with a $10k\Omega$ load, making the devices ideal in low-supply voltage applications.

Power Supplies and Layout

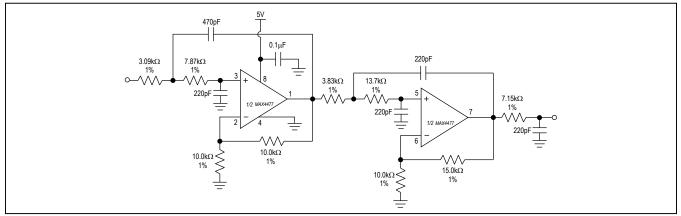
The MAX4475–MAX4478/MAX4488/MAX4489 operate from a single +2.7V to +5.5V power supply or from dual supplies of ± 1.35 V to ± 2.75 V. For single-supply operation, bypass the power supply with a 0.1μ F ceramic

SOT23, Low-Noise, Low-Distortion, Wide-Band, Rail-to-Rail Op Amps

Typical Application Circuit



Typical Operating Circuit



capacitor placed close to the V_{DD} pin. If operating from dual supplies, bypass each supply to ground.

Good layout improves performance by decreasing the amount of stray capacitance and noise at the op amp's inputs and output. To decrease stray capacitance, minimize PC board trace lengths and resistor leads, and place external components close to the op amp's pins.

Typical Application Circuit

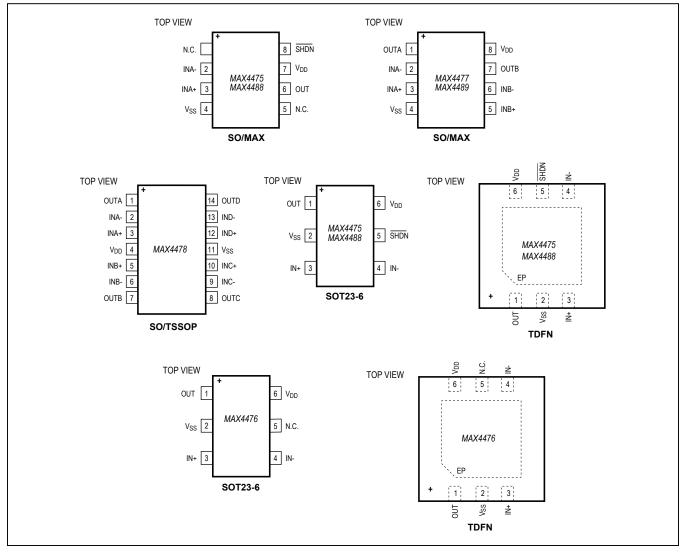
The *Typical Application Circuit* shows the single MAX4475 configured as an output buffer for the MAX5541 16-bit DAC. Because the MAX5541 has an unbuffered voltage output, the input bias current of the op amp used must be less than 6nA to maintain 16-bit accuracy. The MAX4475 has an input bias current of only 150pA (max), virtually eliminating this as a source of error. In addition, the MAX4475 has excellent openloop gain and common-mode rejection, making this an excellent output buffer amplifier.

DC-Accurate Lowpass Filter

The MAX4475–MAX4478/MAX4488/MAX4489 offer a unique combination of low noise, wide bandwidth, and high gain, making them an excellent choice for active filters up to 1MHz. The *Typical Operating Circuit* shows the dual MAX4477 configured as a 5th order Chebyschev filter with a cutoff frequency of 100kHz. The circuit is implemented in the Sallen-Key topology, making this a DC-accurate filter.

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Pin Configurations



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Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4475AUT+T	-40°C to +125°C	6 SOT23	AAZV
MAX4475AUA+	-40°C to +125°C	8 µMAX	—
MAX4475ASA+	-40°C to +125°C	8 SO	—
MAX4475ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADD
MAX4475AUT/V+T	-40°C to +125°C	6 SOT23	+ACQQ
MAX4476AUT+T	-40°C to +125°C	6 SOT23	AAZX
MAX4476ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADF
MAX4477AUA+	-40°C to +125°C	8 µMAX	—
MAX4477AUA+	-40°C to +125°C	8 µMAX	—
MAX4477AUA/V+T	-40°C to +125°C	8 µMAX	+AA/V
MAX4477ASA+	-40°C to +125°C	8 SO	—
MAX4478AUD+	-40°C to +125°C	14 TSSOP	_
MAX4478AUD/V+	-40°C to +125°C	14 TSSOP	—
MAX4478ASD+	-40°C to +125°C	14 SO	—
MAX4488AUT+T	-40°C to +125°C	6 SOT23	AAZW
MAX4488AUA+	-40°C to +125°C	8 µMAX	—
MAX4488ASA+	-40°C to +125°C	8 SO	—
MAX4488ATT+T	-40°C to +125°C	6 TDFN-EP*	+ADE
MAX4489AUA+	-40°C to +125°C	8 µMAX	_
MAX4489AUA/V+T	-40°C to +125°C	8 µMAX	_
MAX4489ASA+	-40°C to +125°C	8 SO	_

+Denotes a lead(Pb)-free/RoHS-compliant package. *EP = Exposed pad (connect to V_{SS}). /V denotes an automotive qualified part.

T = Tape and reel.

Chip Information

PROCESS: BICMOS

Selector Guide

PART		GAIN BW (MHz)	STABLE GAIN (V/V)	NO. OF AMPS	SHDN
MAX44	75	10	1	1	Yes
MAX44	76	10	1	1	—
MAX44	77	10	1	2	—
MAX44	78	10	1	4	—
MAX448	38	42	5	1	Yes
MAX448	39	42	5	2	_

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	12/09	Added lead-free designations and an automotive part to the Ordering Information and added input current spec in Absolute Maximum Ratings section	1, 2, 13
5	7/10	Added /V designation to the MAX4475 product and soldering temperature	1, 2
6	6/12	Added /V designation for MAX4489.	13
7	1/18	Added AEC statement to Features section	1
8	7/18	Updated Ordering Information table	14
9	7/18	Updated Absolute Maximum Rating and Package Information	2, 14
10	8/18	Updated Package Information section	2–4
11	4/19	Updated General Description and Ordering Information section	1, 16

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